Sm earing of the phase transition in Ising systems with planar defects

Thom as Vojta

Departm ent of Physics, University of Missouri - Rolla, Rolla, MO 65409, USA

A bstract. We show that phase transitions in Ising systems with planar defects, i.e., disorder perfectly correlated in two dimensions are destroyed by smearing. This is caused by e ects similar to but stronger than the Gri ths phenomena: Exponentially rare spatial regions can develop true static long-range order even when the bulk system is still in its disordered phase. C lose to the smeared transition, the order parameter is very inhom ogeneous in space, with the therm odynamic (average) order parameter depending exponentially on temperature. We determ ine the behavior using extrem al statistics, and we illustrate the results by computer simulations.

1. Introduction

P hase transitions in random systems remain one of the important and only partially solved problems in statistical physics. Originally, it was thought that even weak disorder destroys any critical point because the disordered system divides itself up into spatial regions which undergo the transition at di erent temperatures, leading to a sm eared transition in which there would be no sharp singularities in therm odynam ic quantities (see [1] and references therein). However, it was soon found that classical continuous phase transitions are generically sharp in the presence of weak, short-range correlated disorder. If a clean critical xed point (FP) fulls the Harris criterion [2]

2=d, where is the correlation length exponent and d is the spatial dimensionality, the disorder decreases under coarse graining. The system becomes asymptotically hom ogeneous at large length scales. Thus, the clean critical point is perturbatively stable against disorder, and the critical behavior of the random system is identical to that of the corresponding clean system . M acroscopic observables are self-averaging at the critical point, i.e., the relative width of their probability distributions goes to zero in the therm odynam ic lim it [3,4].

Even if the H arris criterion is violated, the transition will generically remain sharp, but the critical behavior will be di erent from that of the clean system. D epending on the fate of the disorder under coarse graining it can either be of nite or of in nite disorder type. In the rst case the system remains inhom ogeneous at all length scales with the relative strength of the inhom ogeneities approaching a nite value for large length scales. These transitions are controlled by renorm alization group (RG) xed points with nite disorder. M acroscopic observables are not self-averaging, the relative width of their probability distributions approaches a size-independent constant [3,4]. E xam ples of critical points in this class include the dilute three-dimensional Ising m odel or classical spin glasses. The second case occurs when the relative m agnitude of

the inhom ogeneities increases without limit under coarse graining. The corresponding xed points are called in nite-disorder xed points. Here, the probability distributions of m acroscopic variables become very broad (on a logarithm ic scale) with the width increasing with system size. This can lead to activated rather than the usual power-law scaling at the critical point. A fam ous classical example of an in nite-disorder critical point occurs in the M cC oy-W u m odel [5].

In recent years, another aspect of phase transitions in disordered systems, the G ri ths phenom ena, has regained a lot of attention. G ri ths phenom ena are nonperturbative e ects of mare disorder uctuations in the vicinity of a phase transition. They can be understood as follows: Disorder in general decreases the critical tem perature T_c from its clean value T_c⁰. In the tem perature region T_c < T < T_c⁰ the system does not display global order. However, in an in nite system one will nd arbitrarily large regions that are devoid of in purities with a sm all but nonzero probability. These rare regions or 'G ri the islands' are locally in the ordered phase while the bulk system is still in the disordered phase. Their uctuations are very slow because ipping them requires changing the order parameter in a large volume. Griths [6] was the rst to show that this leads to a non-analytic free energy everywhere in the region $T_c < T < T_c^0$, which is now known as the Gri ths phase [7] or the Gri ths region. In generic classical systems, the contribution of the Gri ths singularities to therm odynam ic (equilibrium) observables is very weak since the singularity in the free energy is only an essential one [6,8]. In contrast, the consequences for the dynam ics are much more severe with the rare regions dom inating the behavior for long times. In the Gri the region, the spin autocorrelation function C (t) decays very slow by with time t, like ln C (t) $(\ln t)^{=(d-1)}$ for Ising systems $t^{=2}$ for H eisenberg system s [11,13]. M ore recently, these $[7,9\{12], \text{ and like ln C (t)}$ results have been con med by rigorous calculations for the equilibrium [14,15] and dynam ic [16] properties of disordered Ising m odels.

In many real systems, the disorder is not generated by point-like defects but by dislocations or disordered layers or grain boundaries. O ften, extended in purities in a d-dimensional system can be modeled by disorder perfectly correlated in $d_c = 1$ or 2 dimensions but uncorrelated in the remaining $d_2 = d$ dimensions. While it is generally accepted that long-range disorder correlations increase the e ects of the in purities, their in uence on the phase transition has been controversial. Early RG work [17] based on a single expansion in = 4 d did not produce a critical xed point. This was interpreted as a smeared transition or a rst order one [18,19]. However, an additional expansion in the number d_c of correlated dimensions [20(22] cured this problem and gave rise to critical xed points with conventional power-law scaling. Further support for the sharp transition scenario came from M onte-C arlo simulations of a 3D Ising model with planar defects [23]. All the perturbative RG studies miss, how ever, the e ects of rare regions and G ri ths phenom ena. These e ects have been studied in detail in the already m entioned M oc oy-W u m odel [5], a disordered 2D Ising m odel in which the disorder is perfectly correlated in one dim ension and uncorrelated in the other. The transition in thism odel was originally thought to be sm eared. It was later found that it is sharp but of in nite-disorder type [24,25]. Sim ilar behavior has been found in several random quantum systems which are related to classical systems with linear defects [26{31]. Based on these results it was believed for a long time that phase transitions generically remain sharp even in the presence of extended disorder.

In this paper we show, how ever, that this belief is not generally true. Speci cally, we show that for Ising order parameter symmetry, planar defects destroy the sharp

continuous phase transition via e ects which are similar to but stronger than the usual G ri ths phenom ena: In systems with planar defects true static bng-range order can develop on isolated rare regions. As a result, the order parameter is very inhom ogeneous in space close to the sm eared transition, and the therm odynamic order parameter depends exponentially on temperature. We also show that this disorder-induced sm earing generically occurs in an entire class of transitions in system s with extended disorder. The paper is organized as follows. In Sec. 2, the model is introduced, and the mechanism for the sm earing of the transition is explained. In Sec. 3 we use Lifshitz tail arguments to determ ine the behavior in the 'tail' of the rounded transition, i.e., for a very low concentration of ordered islands. Section 4 is devoted to a num erical study of a three-dimensional in nite-range Ising model which illustrates the sm earing of the phase transition. Finally, in Sec. 5 we discuss the generality of the disorder-induced sm earing, the relation to G ri ths phenomena, favorable conditions for observing the sm earing, and the in uence of the order parameter symmetry.

2. R are regions, inhom ogeneous order, and sm earing

For de niteness we consider a d-dimensional ⁴ theory with random $-T_c$ type disorder completely correlated in the $d_c = 2$ directions x_1 and x_2 but uncorrelated in the remaining $d_? = d$ directions x_3 ;:::; x_d . The action is given by

$$S = d^{d}r (r) t + t(r_{2}) \qquad (l_{r}^{2} (r) + u d^{d}r^{4}(r) : \qquad (1)$$

Here (r) is a scalar eld, t is the dimensionless distance from the clean critical point and $t(\underline{r}_{1})$ introduces the quenched disorder. r_{2} is the projection of r on the uncorrelated directions x_{3} ;:::; x_{d} . We consider two dimension types of disorder. In the rst type, Poisson (or dilution) disorder, $t(\underline{r}_{2})$ is given by

$$t(r_{2}) = V[r_{2} r_{2} r_{3}(1)]$$
 (2)

where $r_{?}$ (i) are the random positions of planar in purities of spatial density c_{r} and V ($r_{?}$) is a non-negative short-ranged in purity potential. The second type of disorder is a G aussian distribution with zero m ean and a correlation function

$$t(p_{i}) t(p_{i}^{0}) = {}^{2} (p_{i} p_{i}^{0}) :$$
 (3)

Now consider the elects of rare disorder uctuations in this system : A nalogous to the G ri ths phenom ena, there is a smallbut nite probability for nding large spatial regions in r_2 direction which are more strongly coupled than the bulk system. For P oisson disorder, these are regions devoid of in purities while for G aussian disorder it would be regions with a negative average h t(r_2) i. These rare regions can be locally in the ordered phase, even if the bulk system is still in the disordered phase. For P oisson disorder which full ls t(r_2) > 0 this starts to happen right below the clean transition, i.e., for t < 0 [32] while for the unbounded G aussian disorder, locally ordered rare regions exist for all t. Since the defects in our system are planar, the rare regions are in nite in the x_1 and x_2 directions but nite in the remaining directions. This is a crucial di erence to system s with uncorrelated disorder, where the rare regions are nite objects (see Sec. 5). In our system , each rare region is therefore equivalent to a two-dimensional Ising system and can undergo a real phase transition independently of the rest of the system. Thus, for planar defects, those rare regions which are in the

ordered phase will develop a non-zero static order param eter which can be aligned by an in nitesim ally sm all interaction or an in nitesim ally sm all eld.

The resulting phase transition is very di erent from conventional continuous phase transitions, be it transitions controlled by clean or nite-disorder or even in nite-randomness xed points. In all of those cases, which represent \sharp" phase transitions, a non-zero order parameter develops as a collective e ect of the entire system, accompanied by a diverging correlation length in all directions. In contrast, in a system with planar defects, the order parameter develops very inhom ogeneously in space with di erent parts of the system (i.e., di erent r_2 regions) ordering independently at di erent t. Correspondingly, the correlation length in r_2 direction remains nite for all temperatures. This de nes a smeared transition. We thus conclude that planar defects lead to a smearing of the phase transition.

Above, we have de ned a sm eared continuous phase transition via the behavior of correlation length. We now characterize it via the behavior of the free energy density or other global therm odynam ic variables. Two qualitatively di erent cases of sm eared transitions must be distinguished. If the disorder distribution is unbounded in the sense that it perm its regions with a local $T_c = 1$ (system (1) with G aussian disorder falls into this class), the total (average) order parameter is non-zero for all tem peratures, and the free energy density is analytic. In contrast, if the disorder distribution is bounded, there is a true param agnetic phase with zero order parameter starts to develop on rare spatial regions, accompanied by an essential singularity in the free energy density for noting a rare region). This singularity is weaker than the power-law singularities at the sharp transitions mentioned above. The model (1) with Poisson disorder falls into this second class, with T_0 being identical to the critical tem perature of the pure system.

3. Lifshitz tail argum ents

In this section we use extrem alstatistics to derive the leading therm odynam ic behavior in the 'tail' of the sm eared transition, i.e., in the parameter region where a few islands have developed static order but their density is so sm all that they can be treated as independent. The approach is similar to that of Lifshitz [33] and others for the description of the tails in the electronic density of states. We ext consider the Poisson type of disorder and later describe the di erences for G aussian disorder.

3.1. Poisson disorder

The probability w of nding a large region of linear size L_R (in r_2 -space) devoid of any in purities is, up to pre-exponential factors, given by

$$w \exp\left(c d_{e}^{\Omega_{2}} \right)$$
: (4)

As discussed in Sec. 2, such a rare region develops static long-range order at some $t_c (L_R)$ below the clean critical point $t_c^0 = 0 \times T$ he value of $t_c (L_R)$ varies with the size of the region: The largest islands develop long-range order closest to the clean

z Note that global therm odynam ic variables (which average over the entire sample) do not resolve the strong spatial inhom ogeneities which are the hallm ark of a sm eared transition, and thus do not provide com plete inform ation about the transition

x W e use the bare value, $t_c^0 = 0$, for the clean critical reduced tem perature. For our purpose, the distinction between the bare and the renorm alized t is of no importance.

Sm earing of the phase transition in Ising systems with planar defects

critical point. F in ite size scaling (for the clean system, because the island is devoid of in purities) yields

$$\mathbf{t}_{\mathrm{C}}^{0} \quad \mathbf{t}_{\mathrm{C}}(\mathbf{L}_{\mathrm{R}}) = \mathbf{j}_{\mathrm{C}}(\mathbf{L}_{\mathrm{R}})\mathbf{j} = \mathbf{A}\mathbf{L}_{\mathrm{R}} \tag{5}$$

where is the nite-size scaling shift exponent and A is the amplitude for the crossover from d dimensions to a slab geometry in nite in two dimensions but nite in $d_2 = d - 2$ dimensions. Combining (4) and (5) we obtain the probability for noting a rare region which becomes critical at t_c as

$$w(t_c) \exp(B_{t_c})^{d_2} =) \quad (fort! 0) \quad (6)$$

where the constant B is given by $B = cA^{d_2 =}$. The total (or average) orderparam eter m is obtained by integrating over all rare regions which are ordered at t, i.e., all rare regions having $t_c > t$. Since the functional dependence on t of the order param eter on a given island is of power-law type it does not enter the leading exponentials but only the pre-exponential factors. Therefore we obtain to exponential accuracy

$$m \exp(B_{\pm j}^{d_2}) (fort! 0):$$
 (7)

The hom ogeneous magnetic susceptibility consists of two dimensions contributions, one from the islands on the verge of ordering and one from the bulk system still deep in the disordered phase. The bulk system provides a nite, noncritical background susceptibility throughout the tail region of the smeared transition. In order to estim ate the contribution of the islands consider the onset of local ordering at the clean critical tem perature $t_c^0 = 0$. U sing (6) for the density of the islands we can estim ate

dtt
$$\exp(Bt^{d_2})$$
 (8)

which is nite because the exponentially decreasing island density overcomes the power-law divergence of the susceptibility of an individual island. Here is the clean susceptibility exponent and is related to a lower cuto for the island size. Once ordered islands exist they produce an elective background magnetic eld everywhere in space which cuts o any possible divergence. Therefore we conclude that the hom ogeneous magnetic susceptibility does not diverge anywhere in the tail region of the sm eared transition. How ever, there is an essential singularity at the clean critical point produced by the vanishing density of ordered islands.

0

The spatial magnetization distribution in the tail of the smeared transition is very inhom ogeneous. On the already ordered islands, the local order parameter m (r) is of the same order of magnitude as in the clean system. A way from these islands it decays exponentially with the distance from the nearest island. The probability distribution P [logm (r)] will therefore be very broad, ranging from logm (r) = O (1) on the largest islands to logm (r) ! 1 on sites very far away from an ordered island. The typical local order parameter m typ can be estimated from the typical distance of any point to the nearest ordered island. From (6) we obtain

$$\mathbf{r}_{\text{typ}} = \exp\left(\mathbf{B} \, \mathbf{j} \, \mathbf{j}^{\, \mathbf{d}_2 \, \mathbf{e}} = \mathbf{d}_2\right) \, \mathbf{i} \tag{9}$$

At this distance from an ordered island, the local order param eter has decayed to

$$m_{typ} e^{r_{typ}=0} exp C exp(B jj^{d_2}=d_2)$$
 (10)

where $_0$ is the bulk correlation length (which is nite and changes slow ly throughout the tail region of the sm eared transition) and C is constant. A comparison with (7) gives the relation between m $_{\rm typ}$ and the therm odynam ic order parameterm,

$$j\log m_{typ} j m^{1=d_2}$$
: (11)

Thus, m_{typ} decays exponentially with m indicating an extremely broad local order parameter distribution. In order to determ ine the functional form of the local order parameter distribution, rst consider a situation with just a single ordered island at the origin of the coordinate system. For large distances r the magnetization falls o exponentially like $m(r) = m_0 e^{\frac{r_2}{r_2} = 0}$. The probability distribution of $x = \log[m(r)] = \log m_0$ $r_2 = 0$ can be calculated from

$$P(\dot{\mathbf{x}}) = \frac{dN}{dx} = \frac{dN}{dr_2} \frac{dr_2}{dx} = \frac{dN}{dr_2} \quad \mathbf{x} = \frac{dN}{dr_2} \quad \mathbf{x}$$

where dN is the num ber of sites at a distance from the origin between $r_{?}$ and $r_{?} + dr_{?}$ or, equivalently, having a logarithm of the local magnetization between x and x + dx. For large distances we have \dot{x}_{j} \dot{x} . Therefore, the probability distribution of log m generated by a single ordered island takes the form

$$P[log(m)] jlog(m)^{d_{2}}$$
 (form 1): (13)

In the tail region of the sm eared transition the system consists of a few ordered islands whose distance is large compared to $_0$. The probability distribution of log [m (r)] thus takes the form (13) with a lower cuto corresponding to the typical island-island distance and an upper cuto corresponding to a distance $_0$ from an ordered island.

3.2. Finite-size e ects

It is important to distinguish e ects of a nite size L_c in the correlated directions and a nite size L_c in the uncorrelated directions. If L_c is nite but L_c is in nite static order on the rare regions can still develop. In this case, the sam ple contains only a nite number of islands of a certain size. As long as the number of relevant islands is large, nite size-e ects are governed by the central limit theorem. How ever, for t ! 0 very large and rare islands are responsible for the order param eter. The number N of islands which order at t_c behaves like N $L_c^{d_c}$ w (t_c). When N becomes of order one, strong sam ple-to-sam ple uctuations arise. U sing (6) for w (t_c) we nd that strong sam ple to sam ple uctuations start at

$$\mathbf{j}_{\mathbf{L}_{?}} \mathbf{j} \quad \frac{\mathbf{d}_{?}}{\mathbf{B}} \log(\mathbf{L}_{?}) \qquad : \qquad (14)$$

Thus, nite size e ects are suppressed only logarithm ically.

A nalogously, one can study the onset of static order in a sam ple of nite size L $_{?}$ (i.e., the ordering tem perature of the largest rare region in this sam ple). For small sam ple size L $_{?}$, the probability distribution P (t_c) of the sam ple ordering tem peratures t_c will be broad because some sam ples do not contain any large islands. With increasing sam ple size the distribution becomes narrower and moves towards the clean t⁰_c because more sam ples contain large islands. The maximum t_c coincides with t⁰_c corresponding to a sam ple without impurities. The lower cuto corresponds to an island size so small that essentially every sam ple contains at least one of them. C onsequently, the width of the distribution of critical tem peratures in nite-size sam ples is governed by the sam e relation as the onset of the uctuations,

$$t_{c} = \frac{d_{?}}{B} \log (L_{?}) \qquad (15)$$

We now turn to nite-size e ects produced by a nite extension L $_{\rm C}$ of the system in the correlated directions. In this case, the true static order on the rare regions

is destroyed. W hether or not the system develops long-range order depends on the number d₂ of uncorrelated dimensions. If d₂ = 1 no static long-range order can develop, i.e. the transition is rounded by conventional nite size e ects in addition to the disorder-induced smearing. In contrast, for d₂ > 1 a true phase transition is possible but requires a nite interaction between the islands of the order of the tem perature. This restores a sharp phase transition at a reduced tem perature t_c (L_C). To estimate the relation between L_C and t_c (L_C) we note that the interaction between two planar rare regions of linear size L_C is proportional to L_C² and decays exponentially with their spatial distance r, E_{int} $I_{C}^{2} \exp(r=_{0})$, where ₀ is the bulk correlation length. W ith the typical distance given by (9) we obtain a double exponential dependence between L_C and the critical reduced tem perature t_c (L_C):

$$\log(\log L_{\rm C}) \quad j_{\rm e} j^{\rm d_2} = : \tag{16}$$

3.3. Gaussian disorder

In this subsection we apply Lifshitz tail arguments to the case of -correlated G aussian disorder [34]. In contrast to the positive denite Poisson disorder, the G aussian disorder is unbounded for t(r)! 1. Therefore, locally ordered islands can exist for allt, and, in principle, the tail region of the sm eared transition stretches to t! 1. In order to determ ine the probability for noing a rare region which orders at a certain t_c, i.e., the G aussian equivalent to (6), consider an island of linear size L_R . The average disorder value h ti in this region has the distribution i

P[h ti] exp
$$I_{R}^{d_{2}}$$
 h $t_{I}^{2} = (2)$: (17)

A coording to nite size scaling, an island of size L_R with an average disorder value of h ti will develop static order at $t_c = h$ ti A_R^L . For xed island size, the probability distribution of t_c reads h i

P (t_c) exp
$$L_{R}^{d_{2}}$$
 (t_c + A L_{R})²=(2) : (18)

W e now calculate the stationary point of the exponent with respect to L_R (saddle point approximation) to determ ine which island size gives the dom inating contribution. For $(2 \quad d_i =) > 0$, this leads to

$$(2 \quad d_{i} =) A L_{r} = t_{c} d = :$$
 (19)

This implies that small but very deep uctuations are responsible for the tail of the sm eared transition (in contrast to Poisson disorder where the tail is produced by the largest islands). Inserting into (18) gives the desired probability as a function of t_c ,

$$w(t_c) = \exp(Bt_c^{2d_2})$$
 (20)

where B is a constant. In contrast, for $(2 \quad d_i =) < 0$, the main contribution comes from arbitrarily small islands. In this case the -correlated disorder is unphysical and should be replaced by a distribution with a nite correlation length. The resulting w (t_c) is then purely G aussian. In the following we will not consider this case.

Starting from (20), one can derive the leading behavior in the tail of the sm eared transition (t ! 1). Integrating over all ordered islands gives the total m agnetization

$$m \exp(Bt_{2}^{2} d_{2}^{d}):$$
 (21)

The typical local magnetization m_{typ} decays exponentially with the average magnetization m, i.e. (11) also holds in the Gaussian case as can be easily seen by

starting the derivation from (20) rather than (6). For samples of nite size in the uncorrelated directions the onset of sample-to-sample uctuations and the width of the sample ordering temperatures follow

$$t_{L_2}$$
 t_c $(\log L_2)^{1=(2 d_2 = 1)}$: (22)

If the samples are of nite size in the correlated directions but in nite in the uncorrelated ones (and if $d_2 > 1$) a sharp phase transition is restored. The relation between L_c and t_c is double-exponential:

$$\log(\log L_{\rm C}) \quad t_{\rm C}^{2 \, d_2} = t \tag{23}$$

A comparison of the results for Gaussian and Poisson disorder shows that the functional form of the therm odynamic relations at the smeared transition depends on the form of the disorder and is thus not universal.

4. Num erical results

4.1. M odel and m ethod

To illustrate the sm earing of the phase transition we now show results from a numerical simulation of a 3D Ising model with planar bond defects, i.e., $d_c = 2$ and $d_r = 1$. A s discussed above, the sm earing of the phase transition is the result of exponentially rare events. Therefore large system sizes are required to observe it. In order to reach su ciently large sizes with a reasonable e ort and to retain the possibility of static order on an isolated rare region, we consider a model with in nite-range interactions in the correlated directions (parallel to the defects) but short-range interactions in the uncorrelated direction (perpendicular to the defect planes). W hile the in nite-range model will not be quantitatively comparable to a short-range model, it provides a simple example for the rounding mechanism introduced in Sec. 2. Moreover, since the rounding mechanism only depends on the existence of static order on the rare regions but not on any details, we expect that the results will qualitatively valid for a short-range model, too (with the appropriate changes to the exponents in the relations of a 3D. Indeed, prelim inary results [35] of M onte-C arlo simulations of a 3D short-range Ising model with planar defects fully agree with this expectation.

The Hamiltonian considered in this section reads

$$H = \frac{1}{L_{C}^{2}} X_{x,y,z,y^{0};z^{0}} S_{x,y,z} S_{x+1,y^{0};z^{0}} \frac{1}{2L_{C}^{2}} X_{x,y,z,y^{0};z^{0}} J_{x} S_{x,y,x} S_{x,y^{0}z^{0}} h_{x,y,z}^{X} S_{x,y,z} (24)$$

Here x;y;z are the integer-valued coordinates of the Ising spins. The magnetic eld h acts as a symmetry breaker, it will be set to a small but non-zero value, typically $h = 10^{-10}$. L_C is the system size in the y and z directions. The planar defects are parallel to the (y;z)-plane. They are introduced via disorder in the inplane coupling J_x which is a quenched binary random variable with the distribution $P(J) = (1 \ c) \ (J \ 1) + c \ (J \ d) with <math>J_d < 1$. Here, c is the defect concentration and the deviation of J_d from 1 m easures the strength of the defects. For our calculations we use $J_d = 0$, i.e., very strong defects in an easy way is the main advantage of this binary disorder distribution. However, it also has unwanted consequences, viz. log-periodic oscillations of m any observables as functions of the distribution and unrelated to the sm earing considered here; we will not discuss them further.

Sm earing of the phase transition in Ising systems with planar defects

Because the interaction is in nite-ranged in the correlated (y and z) directions, these dimensions can be treated exactly: W = introduce the plane magnetizations

$$m_{x} = \frac{1}{L_{c}^{2}} X_{x;y;z} \qquad (25)$$

into the partition function and integrate out the original Ising variables $S_{x,y,z}$. In the therm odynam ic lim it, L_c ! 1, the resulting integral can be solved using saddle point approximation. This leads to a set of coupled local mean-eld equations

$$m_x = \tanh [(m_{x-1} + J_x m_x + m_{x+1} + h)=T];$$
 (26)

where T is the temperature (we work in units where the Boltzmann constant is $k_B = 1$). In the clean case, c = 0, all J_x are equal to 1. Consequently, all local mean-eld equations are identical, reading $m = \tanh[(3m + h)=T]$. The clean critical temperature of the model (24) is therefore $T_c^0 = 3$.

In the presence of disorder, the local mean-eld equations (26) have to be solved numerically. We employ a simple self-consistency cycle: All m_x are initially set to $m_x = 0.1$. We then insert the current values of m_x into the rhs. of (26) and calculate new values m_x^{new} which are then put into the rhs. and so on. This is repeated until the change $jn_x^{new} = m_x j$ falls below a threshold of 10⁻¹² for all x. This method is very robust, it never failed to converge, but it can be very slow in the tail region of the transition where ordered islands coexist with large disordered regions. In this region sometimes several 1000 iterations were necessary. However, in contrast to m ore sophisticated methods like the Newton-Raphson method no matrix inversions are required. Therefore we were able to simulate very large systems up to $L_2 = 10^6$.

W e also note that the model (24) is similar to the mean-eld M cC oy-W u model considered in Ref. [37]. The raw data obtained in this paper (L₂ up to 1000) are very similar to ours, but they were interpreted in terms of conventional power-law critical behavior with an unusually large order parameter exponent 3:6. This may be partially due to an unfortunate choice of parameters (in particular, a higher in purity concentration of c = 0.5) which makes it harder to observe the exponential tail of the smeared transition. We will come back to this question in Sec. 5.

4.2. Therm odynam ic magnetization and susceptibility

In this subsection we present numerical results for the total magnetization $m = L_2^{1} m_x m_x$ and the hom ogeneous susceptibility = 0 m = 0 h. The left panel of gure 1 gives an overview over the behavior of m and as functions of tem perature T for size $L_2 = 1000$ and in purity concentration c = 0.2. The data are averages over 1000 disorder realizations. (Therm odynamic quantities involve averaging over the whole system. Thus ensemble averages rather than typical values give the correct in nite system approximation.) At a rst glance these data suggest a sharp phase transition close to T = 2.96. How ever, a closer inspection of the transition region in the right panel of gure 1 shows that the singularities are rounded. If this smearing was a conventional nite-size e ect the magnetization curve should become e sharper with increasing L_2 and the susceptibility peak should diverge. This is not the case here, both the magnetization and the susceptibility data are essentially size-independent. We conclude that the smearing is an intrinsic e ect of the in nite system.

In order to compare the total magnetization data with the analytical Lifshitz tail prediction (7) we need to determ ine the value of the clean nite-size scaling shift

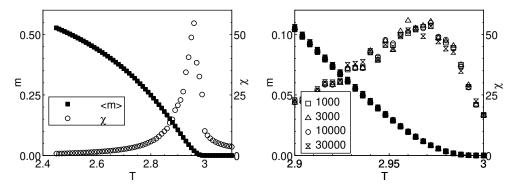
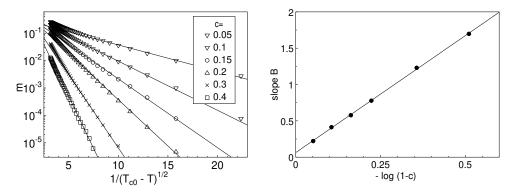


Figure 1. Left: Magnetization m and susceptibility for $L_2 = 1000$; c = 0.2. Right: Magnetization and susceptibility close to the seeming transition for di erent system sizes L_2 in the uncorrelated direction.

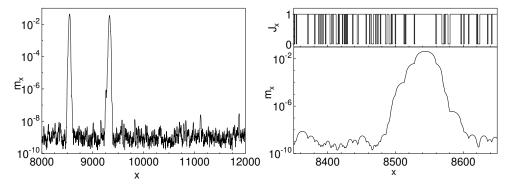


F igure 2. Left: Totalm agnetization m as a function of $(T_c^0 T)^{1=2}$ for several impurity concentrations c. The solid lines is are tot eq. (7) with = 2. Right: D ecay constant B as a function of log(1 c).

exponent for the model (24). Finite-size scaling is governed by the rst appearance of a non-vanishing solution of the linearized clean mean-eld equation in a slab geometry of varying thickness. This equation is equivalent to a one-dimensional Schrodinger equation in a potential well, leading to a clean shift exponent of = 2 and $d_2 = = 1=2$. In the left panel of gure 2, we therefore plot the logarithm of the total magnetization, averaged over 300 samples, as a function of (T_c^0) T) $^{1=2}$ for system size L₂ = 10000 and several in purity concentrations c. For all c, the data follow eq. (7) over several orders of m agnitude in m . Fits of the data to (7) are used to determ ine the decay constants B. The right panel of gure 2 shows that these decay constants depend linearly on log (1 c). This is exactly the expected behavior in a lattice model with binary disorder since the probability for nding an island of size L_R devoid of L_R log(1 c) in purities behaves like $(1 c)^{L_R}$

4.3. Local magnetization

In the tail region of the sm eared transition the system consists of a few rare ordered regions (on su ciently large islands devoid of in purities). These rare regions are far apart, and between them the localm agnetization is exponentially sm all. This behavior



F igure 3. Left: Local magnetization m $_x$ vs. x for a segment of a single sample with size L₂ = 100000, impurity concentration c = 0.2 and temperature T = 2:99. Right: Local magnetization m $_x$ and local coupling constant J_x in the vicinity of one of the ordered islands.

is illustrated in gure 3. The left panel shows the local magnetization of a segment of a large sample in the tail region of the smeared transition. The data show that the local magnetization on the islands is large (0:1) but it drops very rapidly with increasing distance from the islands. This drop-o can be used to estimate the bulk correlation length which is very small in this parameter region, 0 3:::4. Note that the seem ing saturation of the magnetization decrease at m 10⁹ is a result of the nite external eld $h = 10^{-10}$. W ithout eld, the magnetization would drop much further. A comparison of the local magnetization m_x and the local coupling constant J_x in the right panel of gure 3 shows that magnetic order only exists on a su ciently large island devoid of any in purities.

In order to quantify these observations, we have also calculated the probability distribution P ($\log m_x$) of the local magnetization values, or, more precise, their logarithm s. Figure 4 shows this distribution for a single large sample of $L_2 = 20000$, in purity concentration c = 0.2, and temperatures ranging from T = 2.8 (deep in the ordered phase) to T = 2:99 (in the tail of the sm eared transition). C learly, with increasing tem peratures the distribution becom es very broad, even on this logarithm ic scale. Two qualitatively di erent regim es can be distinguished. For tem peratures not too close to the clean critical point (T = 2.80 to 2.96), the distribution is dominated by an exponential decay towards small magnetization values (i.e., towards negative logm) with the decay constant decreasing with increasing temperature. However, once the system enters the rare-region dom inated tail region of the sm eared transition (which, as can be seen from gures 1 and 2, happens roughly at T = 2.96:::2:97 for c = 0.2) the behavior changes: In agreem ent with (13) the probability distribution P (log m x) becom es constant except for a peak at large m agnetization values which we attribute to the behavior of m_x on the ordered islands (eq. (13) was derived from the behavior of the sites not belonging to one of the rare ordered islands).

4.4. Finite-size e ects and sample-to-sample uctuations

In this subsection we present num erical data for the e ects of a nite sample size L $_{?}$ in the uncorrelated direction, i.e., perpendicular to the impurities. E ects of a nite size L $_{C}$ in the correlated directions cannot easily be studied within our approach because

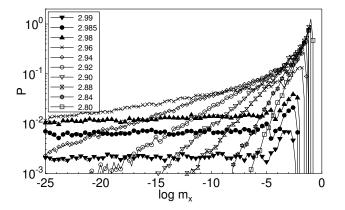


Figure 4. Probability distribution of the local magnetization m_x for single sample of size $L_2 = 200000$, impurity concentration c = 0.2 and several temperatures. The three curves represented by led symbols (T 2:98) are in the asymptotic regime described by eq. (13).

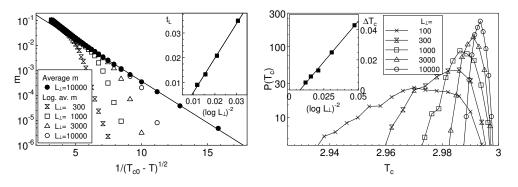


Figure 5. Left: A verage and typical (log. averaged) sample magnetization for c = 0.2 and di erent sample sizes. The inset shows the onset temperature of strong sample-to-sample uctuations (measured by $\underline{t} = T_c^{0} \quad T_L$) as a function of (log L $_2$) 2 . Right: Probability distribution of the sample ordering temperatures for c = 0.2 and di erent sample sizes. The inset shows the width T_c of this distribution as a function of (log L $_2$) 2 .

the lim it L_c ! 1 has been taken in deriving the local mean-eld equations (26).

To investigate sample-to-sample uctuations in a nite-size system we compare the average sample magnetization m_{av} = lm i and the typical sample magnetization m_{typ} = exphlogm i where m is the total magnetization of a sample and h i denotes the average over the disorder. A signi cant di erence between average and typical magnetizations indicates strong sample-to-sample uctuations. The left panel of gure 5 shows the typical magnetizations for four di erent sizes L₂ together with the average magnetization (which is size-independent within the accuracy of this plot) for 300 to 1000 samples, depending on L₂. In the tail region of the smeared transition the typical and average magnetizations deviate from each other by several orders of magnitude. From these data we de ne a temperature T_{L_2} which describes the onset of the sample-to-sample uctuations via m_{av} (T_{L_2})=m typ (T_{L_2}) = e. This temperature shifts to larger values with increasing system size L₂. The inset shows t_{L_2} = T_c^0 T_{L_2} as a function

of $(\log L_2)$ ². The plot shows that t_{L_2} , follow s eq. (14) in good approximation.

The right panel of gure 5 shows the probability distribution of the sam ple critical tem perature which is de ned as the ordering tem perature of the largest rare region in a particular sample (600 to 2000 samples used). As predicted in subsection 32, the distribution becomes narrower with increasing size L₂, and it shifts towards the clean critical tem perature $T_c^0 = 3$. The width T_c of this distribution has been determined from the values where P has decreased by a factor of 1/e. The inset shows that T_c is proportional to (log L₂)² as predicted in eq. (15).

5. D iscussion

To sum m arize, we have shown that true static order can develop on an isolated rare region in an Ising m odel with planar defects. As a result, di erent parts of the system undergo the phase transition at di erent tem peratures, i.e., the sharp transition is sm eared by the defects. In this nal section we discuss the generality of our notings and their relation to G ri ths phenom ena and the H arris criterion. We also discuss favorable conditions for observing the sm earing in experim ents or simulations.

The origins of the sm earing of the phase transition introduced in this paper and of G ri ths phenom ena are very sim ilar, both are caused by rare large spatial regions which are locally in the ordered phase. The di erence between the two e ects is a result of disorder correlations. For uncorrelated or short-range correlated disorder, the rare regions are of nite size. Thus, they cannot develop true static long-range order. Instead, the order parameter uctuates slow ly leading to the G ri ths singularities [6] discussed in Sec. 1. In contrast, if the rare regions are in nite in at least two dimensions, a stronger e ect occurs: the rare regions which are locally in the ordered phase actually develop true static order, and this leads to a sm eared transition. In other words, the same rare regions which would usually produce G ri ths singularities are responsible for the sm earing of the transition in a system with planar defects. The tail of the sm eared transition stretches to where the G ri the temperature would nom ally be, i.e., to T = 1 for G aussian disorder or T = T_c^0 for P oisson disorder. So, the sm eared transition replaces not only the conventional critical point but also the G ri ths phase.

We now discuss under which conditions a phase transition will be smeared by disorder. The arguments given in Sec. 2 in favor of a smeared transition only relied on the dimensionality of the rare regions and the order parameter symmetry. It is therefore expected that all phase transitions with discrete order parameter symmetry are smeared by quenched disorder if the defects are perfectly correlated in at least two dimensions. In systems with linear defects the transition will remain sharp if the interactions are short-ranged. However, if the interactions in the correlated direction fall of as $1=r^2$ or slower, even linear defects can lead to smearing because a 1D Ising model with $1=r^2$ interaction has an ordered phase [38]. This is particularly important [39] for quantum phase transitions in itinerant electronic system swhich can be mapped onto classical system s with $1=\frac{2}{r^2}$ interaction in imaginary time direction.

P hase transitions with continuous order parameter symmetry are more stable against smearing. In systems with short-range interactions the dimensionality of the defects has to be at least three, and in systems with linear or planar defects long-range interactions are required for smearing. It is known [40] that classical XY and H eisenberg systems in dimensions d = 1;2 develop long-range order at nite T only if the interaction falls o more slow by than $1=r^{2d}$. Consequently, in a system with linear

defects the phase transition will only be smeared if the interactions in defect direction fall o more slow by than $1=r^2$ (or more slow by than $1=r^4$ for planar defects).

A third important question concerns the universality of the therm odynamic behavior in the vicinity of the sm eared transition. As can be seen from comparing the results of Poisson and Gaussian disorder, the functional dependence of the magnetization and other observables on the tem perature is not universal, it depends on details of the disorder distribution. Therefore, only the presence or absence of sm earing is universal in the sense of critical phenom ena (i.e., depending on dimensionality and symmetry only) while the therm odynamic relations are non-universal.

O ur fourth remark deals with the relation of the disorder-induced sm earing and the H arris criterion which in the case of extended defects reads [21] > 2=d. We emphasize that the phase transition can be sm eared by planar defects even if the corresponding clean critical point fulls the H arris criterion and appears to be stable. The reason is that the H arris criterion assumes a hom ogeneous transition and studies the behavior of the coarse-grained (root-m ean-square) disorder at large length scales. How ever, the form ation of static order on an isolated nite-size rare region is a nonperturbative nite-length scale e ect in the tail of the disorder distribution. This type of e ects is not covered by the H arris criterion.

We now turn to the question which conditions are favorable for the observation of the sm earing in experiments or simulations. A significant number of large rare regions will only exist if the defect concentration is small, as can be seen from (6). On the other hand, the impurities have to be su ciently strong so that the bulk system is still far away from criticality when the rst rare regions start to order. Thus, the most favorable type of disorder for the observation of the sm earing is a small density of strong in purities. In contrast, for weak in purities the rounding is restricted to a very narrow temperature range below the clean critical temperature and maybe masked by the remainder of the bulk critical uctuations. If the impurity concentration is too high, the exponential drop-o is very fast making it very hard to observe the sm earing. This may also explain why no sm earing was observed in earlier simulations. Speci cally, in R ef. [23] weak impurities (J=J = 0:1) of a high concentration c = 0:5were used. These are unfavorable conditions, and the maximum system size of L = 27used in this simulation was probably too sm all to observe the sm earing.

Finally, we add one remark about the extrem e tail of the smeared transition. In this parameter region, the ordered islands are very far apart and the aligning e ect of the direct island-island interactions is very weak. It is therefore possible that in a real system other interactions play an important role in determining the relative orientation of the order parameter on the islands. This could lead, e.g., to spin glass order in the extrem e tail of the smeared transition.

In conclusion, perfect disorder correlations in one orm ore directions dram atically increase the e ects of the disorder on a phase transition with discrete order param eter sym m etry. Zero-dim ensional defects typically lead to a conventional critical point with power-law scaling. For linear defects the generic behavior seems to be an in nite-random ness critical point [24,25,28] while we have shown here that planar defects generically destroy the sharp transition by sm earing.

A cknow ledgm ents

W e acknow ledge support from the University of M issouri R esearch B oard. Part of this work has been perform ed at the A spen C enter for P hysics.

References

- [1] Grinstein G 1985 Fundam ental Problem s in Statistical Mechanics VI, ed E G D Cohen (New York Elsevier) p.147
- [2] Harris A B 1974 J. Phys. C 7 1671
- [3] A harony A and Harris A B 1996 Phys. Rev. Lett. 77 3700
- [4] W isem an S and D om any E 1998 P hys. Rev. Lett. 81 22
- [5] M oC oy B M and W u T T 1968 Phys.Rev.176 631
- M cC oy B M and W u T T 1969 Phys.Rev.188 982
- [6] Gri ths R B 1969 Phys. Rev. Lett. 23 17
- [7] Randeria M, Sethna J, and Palm er R G 1985 Phys. Rev. Lett. 54 1321
- [8] Bray A J and Huifang D 1989 Phys. Rev. B 40 6980
- [9] Dhar D 1983 Stochastic Processes: Formalism and Applications, ed D S Argawal and S Dattagupta (Berlin:Springer)
- [10] DharD, Randeria M, and Sethna JP 1988 Europhys. Lett. 5 485
- [11] Bray A J 1988 Phys. Rev. Lett. 60 720
- [12] Bray A J and Rodgers G J 1988 Phys. Rev. B 38 9252
- [13] Bray A J 1987 Phys. Rev. Lett. 59 586
- [14] D reyfus H von, K lein A, and Perez J F 1995 C om m un. M ath. Phys. 170 21
- [15] Gielis G and M aes C 1995 J. Stat. Phys. 81 829
- [16] CesiS, M aes C, and M artinelli F 1997 C om m un. M ath. Phys. 189 135 CesiS, M aes C, and M artinelli F 1997 C om m un. M ath. Phys. 189 323
- [17] Lubensky T C 1975 Phys. Rev. B 11 3573
- [18] Rudnick J 1978 Phys. Rev. B 18 1406
- [19] Andelm an D and Aharony A 1985 Phys. Rev. B 31 4305
- [20] Dorogovtsev S N 1980 Fiz. Tverd. Tela (Leningard) 22 321 [Sov. Phys. (Solid State 22 188]
- [21] Boyanovsky D and Cardy J L 1982 Phys. Rev. B 26 154
- [22] DeCesare L 1994 Phys. Rev. B 49 11742
- [23] Lee J C and G ibbs R L 1992 Phys. Rev. B 45 2217
- [24] M cC oy B M 1969 Phys. Rev. Lett. 23 383
- [25] Fisher D S 1992 Phys. Rev. Lett 69 534 Fisher D S 1995 Phys. Rev. B 51 6411
- [26] Young A P and Rieger H 1996 Phys. Rev. B 53 8486
- [27] Pich C, Young A P, Rieger H, and Kawashima N 1998 Phys. Rev. Lett. 81 5916
- [28] Motrunich O, Mau S-C, Huse D A, and Fisher D S 2000 Phys. Rev. B 61 1160
- [29] M a S K, D asgupta C, and Hu C-K 1979 Phys. Rev. Lett. 43 1434
- [30] Bhatt R N and Lee P A 1982 Phys. Rev. Lett. 48 344
- [31] Fisher D S 1994 Phys. Rev. B 50 3799
- [32] Huse D A private communication
- [33] Lifshitz IM 1964 Usp.Fiz.Nauk 83 617 [Sov.Phys.{Usp.7 549] Friedberg R and Luttinger JM 1975 Phys.Rev.B 12 4460
- [34] Halperin B I and Lax M 1966 Phys. Rev. 148 722
- [35] Sknepnek R and Vojta T unpublished
- [36] KarevskiD and Turban L 1996 J.Phys.A 29 3461
- [37] Berche B, Berche P E, Igloi F, and Palagyi G 1998 J. Phys. A 31 5193
- [38] Thouless D J 1969 Phys. Rev. 187 732 Cardy J 1981 J. Phys. A 14 1407
- [39] Vojta T 2003 Phys. Rev. Lett. 90 107202
- [40] Bruno P 2001 Phys. Rev. Lett. 87 137203